

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 6,933,810 B2  
DATED : August 23, 2005  
INVENTOR(S) : Miura et al.

Page 1 of 2

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page,

Item [73], Assignee, add the following:

-- Fujitsu Media Devices Limited, Yokohama (JP) --.

Item [57], ABSTRACT, amend as follows:

-- A surface acoustic wave device includes a piezoelectric substrate having a first surface on which comb-like electrodes are formed, and a second surface, and a support substrate joined to the second surface of the piezoelectric substrate. The piezoelectric substrate is made of lithium, tantalate, and the support substrate is made of sapphire. The following expressions being satisfied:

$$T/t < 1/3$$

$$T/\lambda > 10$$

where T is a thickness of the piezoelectric substrate, t is a thickness of the support substrate, and  $\lambda$  is a wavelength of an IDT forming a resonator including the comb-like electrodes propagated along the first surface of the piezoelectric substrate.

Column 2,

Lines 50-53, should read:

-- where T is a thickness of the piezoelectric substrate, t is a thickness of the support substrate, and  $\lambda$  is a wavelength of an IDT forming a resonator including the comb-like electrodes propagated along the first surface of the piezoelectric substrate. --.

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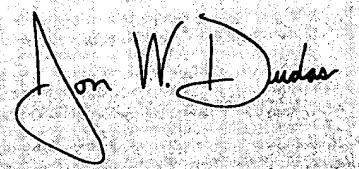
Column 2, line 66 to Column 3, line 2,

Should read:

-- where T is a thickness of the piezoelectric substrate, t is a thickness of the support substrate, and  $\lambda$  is a wavelength of an IDT forming a resonator including the comb-like electrodes propagated along the first surface of the piezoelectric substrate. --.

Signed and Sealed this

Fourteenth Day of March, 2006



JON W. DUDAS  
*Director of the United States Patent and Trademark Office*